

Please amend the Claims as follows:

1-3. (Cancelled)

4. (Currently Amended) A thin-film capacitor element comprising:
an insulative substrate having a via hole filled with a conductive material;

a lower electrode;

a dielectric layer; and

an upper electrode;

wherein the lower electrode, the dielectric layer on the lower electrode, and the upper electrode on the dielectric layer are disposed successively deposited in order on the insulative substrate, at least a portion of the upper and lower electrodes overlap with the dielectric layer therebetween in a direction perpendicular to a face of the substrate.

either one of the lower electrode and the upper electrode connects to an end face of the conductive material in an area not having a dielectric layer; and

the dielectric layer is shaped like a ring to surround the via hole.

5. (Previously Presented) A thin-film capacitor element according to Claim 4, wherein an area between the dielectric layer and the via hole is ring shaped.

6. (Previously Presented) A thin-film capacitor element according to Claim 4, wherein the insulative substrate is made of low-temperature-sintered ceramic.

7. (New) A thin-film capacitor element according to Claim 4, wherein the lower electrode connects to the end face of the conductive material.

8. (New) A thin-film capacitor element according to Claim 7, wherein a substantial portion of the circumference of the lower electrode is not

covered by the dielectric layer and a substantial portion of the circumference of the dielectric layer is not covered by the upper electrode.

9. (New) A thin-film capacitor element according to Claim 4, wherein the upper electrode connects to the end face of the conductive material.

10. (New) A thin-film capacitor element according to Claim 9, wherein the entire circumference of the lower electrode is not covered by the dielectric layer and the entire circumference of the dielectric layer is not covered by the upper electrode.

11. (New) A thin-film capacitor element according to Claim 9, wherein the lower electrode and a portion of the upper electrode surrounding the area that connects to the end face of the conductive material contact the insulative substrate.

12. (New) A thin-film capacitor element according to Claim 11, wherein the dielectric layer is disposed on the insulative substrate between the lower electrode and the portion of the upper electrode that contacts the insulative substrate.